Product data sheet

1. General description

Hyperfast power diode in a TO263 plastic package



2. Features and benefits

- Soft reverse recovery
- · Excellent avalanche energy robustness
- Low leakage current
- · Low thermal resistance
- · Low reverse recovery current
- · Reduces switching losses in associated MOSFET or IGBT

3. Applications

- Active PFC in air conditioner/EV charger/PV
- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- · Half-bridge/full-bridge switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Values		Unit	
Absolute maximum rating								
V_{RRM}	repetitive peak reverse voltage				650		V	
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 105$ °C; Fig. 1; Fig. 2; Fig. 3		30		Α		
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{mb} \le$ 105 °C; square-wave pulse		60		Α		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		270			Α	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse			297		Α	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static ch	aracteristics							
V _F	forward voltage	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>		-	2.10	2.60	V	
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.45	1.90	V	
Dynamic	Dynamic characteristics							
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 200 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	20	24	ns	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	nc	no connected		к I/I л
2	2 K cathode [1]		K — A 001aaa020	
3	A anode			
mb	mb	mounting base; connected to cathod	1 3	

^[1] It is not possible to connect to pin 2 of the TO-263 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYC30MB-650PS	TO263	BYC30MB-650PSJ	Reel	800	TO263d	17-Mar-2023

7. Marking

Table 4. Marking codes

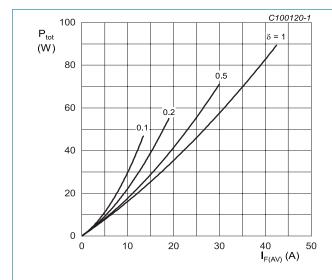
Type number	Marking codes
BYC30MB-650PS	BYC30MB 650PS

8. Limiting values

Table 5. Limiting values

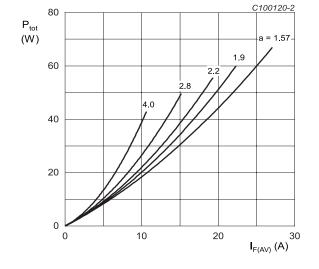
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 105$ °C; Fig. 1; Fig. 2; Fig. 3		30	Α
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 105 °C; square-wave pulse		60	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		270	Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		297	А
T _{stg}	storage temperature			-65 to 175	°C
T _j	junction temperature			-65 to 175	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.465 \text{ V}; R_s = 0.0151 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.465 V; R_s = 0.0151 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

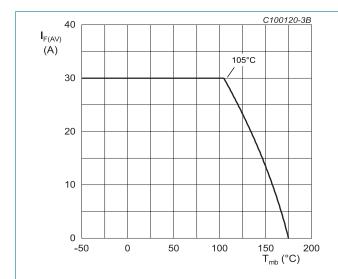


Fig. 3. Forward current as a function of mounting base temperature; maximum values

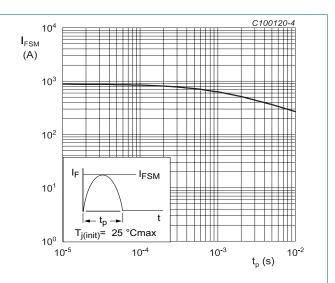


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	0.99	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	60	-	K/W

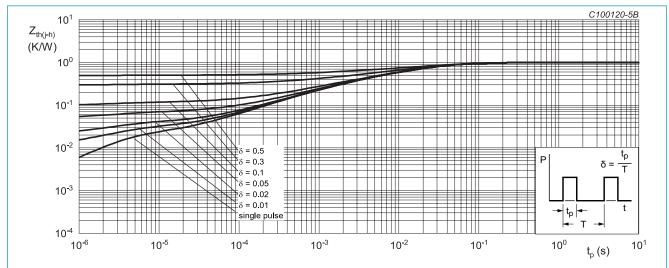
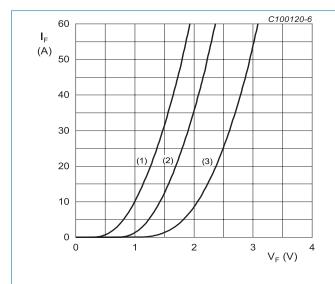


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static characteristics								
V_{F}	forward voltage	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>		-	2.10	2.60	V	
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.45	1.90	V	
I _R	reverse current	V _R = 650 V; T _j = 25 °C		-	0.43	30	μΑ	
		V _R = 650 V; T _j = 150 °C		-	0.08	0.5	mA	
Dynami	c characteristics							
Q _r re	reverse charge	$I_F = 30 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A}/\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	126	-	nC	
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	505	-	nC	
T _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	20	24	ns	
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	67	-	ns	
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	105	-	ns	
I _{RM}	peak reverse recovery currentnon	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	3.8	-	А	
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	9.3	-	А	
S _{factor}	softness factor	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	0.61	-		
E _{as}	non-repetitive avalanche energy	T _{j(init)} = 25 °C		40	-	-	mJ	



 V_o = 1.465 V; R_s = 0.0151 Ω

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) T_i = 25 °C; maximum values

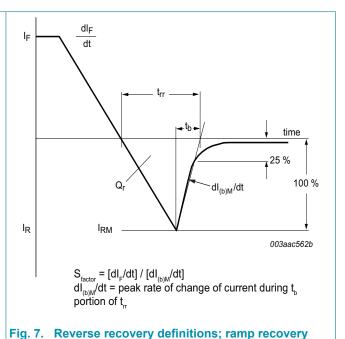
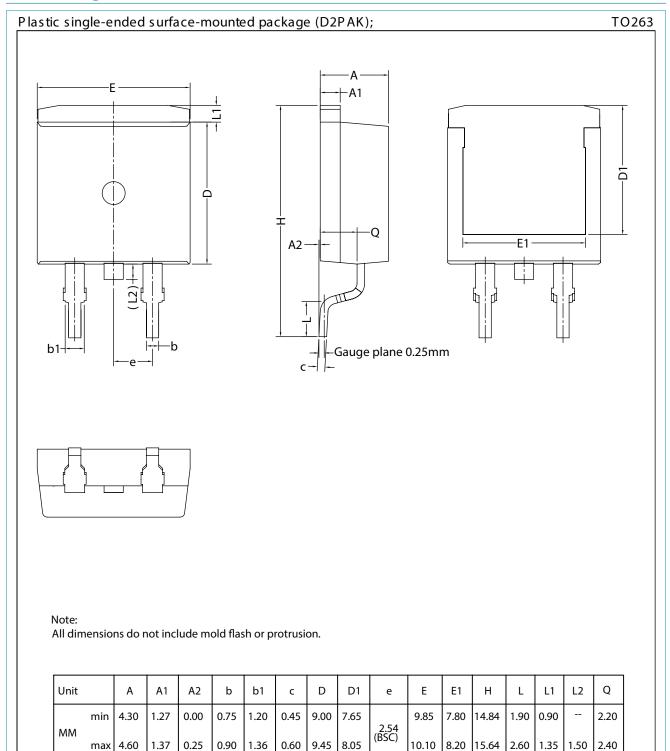


Fig. 6. Forward current as a function of forward voltage

11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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